

DATA SHEET

74F245

Octal transceiver (3-State)

Product specification

1994 Nov 15

IC15 Data Handbook

Philips Semiconductors



PHILIPS

Octal transceiver (3-State)

74F245

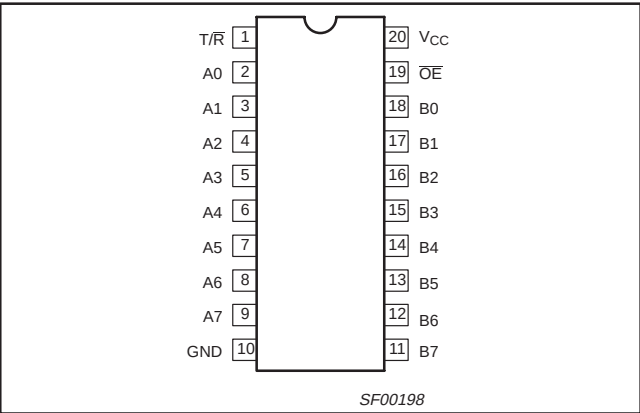
FEATURES

- Octal bidirectional bus interface
- 3-State buffer outputs sink 64mA
- 15mA source current
- Outputs are placed in high impedance state during power-off conditions

DESCRIPTION

The 74F245 is an octal transceiver featuring non-inverting 3-State bus compatible outputs in both transmit and receive directions. The B port outputs are capable of sinking 64mA and sourcing 15mA, producing very good capacitive drive characteristics. The device features an Output Enable ($\overline{OE}$) input for easy cascading and Transmit/Receive ($T/\overline{R}$) input for direction control. The 3-State outputs, B0–B7, have been designed to prevent output bus loading if the power is removed from the device.

PIN CONFIGURATION



TYPE	TYPICAL PROPAGATION DELAY	TYPICAL SUPPLY CURRENT (TOTAL)
74F245	4.0ns	70mA

ORDERING INFORMATION

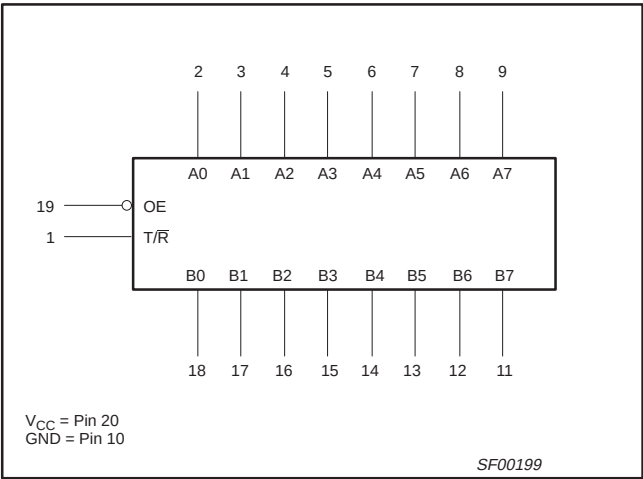
DESCRIPTION	COMMERCIAL RANGE $V_{CC} = 5V \pm 10\%$, $T_{amb} = 0^{\circ}C$ to $+70^{\circ}C$	DRAWING NUMBER
20-Pin Plastic DIP	N74F245N	SOT146-1
20-Pin Plastic SO	N74F245D	SOT163-1
20-Pin Plastic SSOP Type II	N74F245DB	SOT339-1

INPUT AND OUTPUT LOADING AND FAN-OUT TABLE

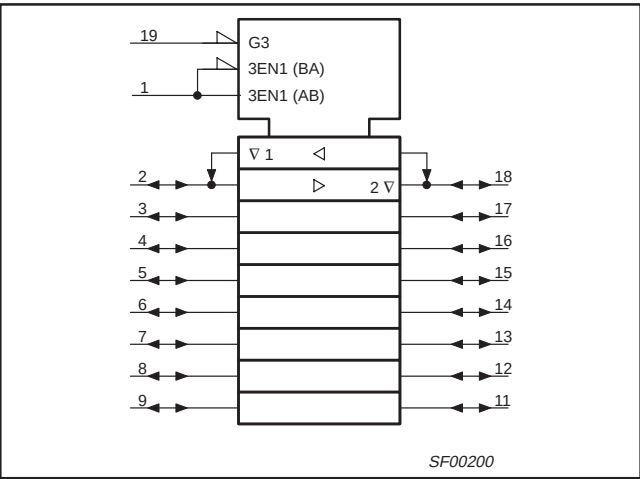
PINS	DESCRIPTION	74F (U.L.) HIGH/LOW	LOAD VALUE HIGH/LOW
A0–A7, B0–B7	Data inputs	3.5/1.0	70 μ A/0.6mA
$\overline{OE}$	Output Enable input (active Low)	1.0/2.0	20 μ A/1.2mA
$T/\overline{R}$	Transmit/Receive input	1.0/2.0	20 μ A/1.2mA
A0–A7	A port outputs	150/40	3.0mA/24mA
B0–B7	B port outputs	750/106.7	15mA/64mA

NOTE: One (1.0) FAST unit load is defined as: 20 μ A in the High state and 0.6mA in the Low state.

LOGIC SYMBOL



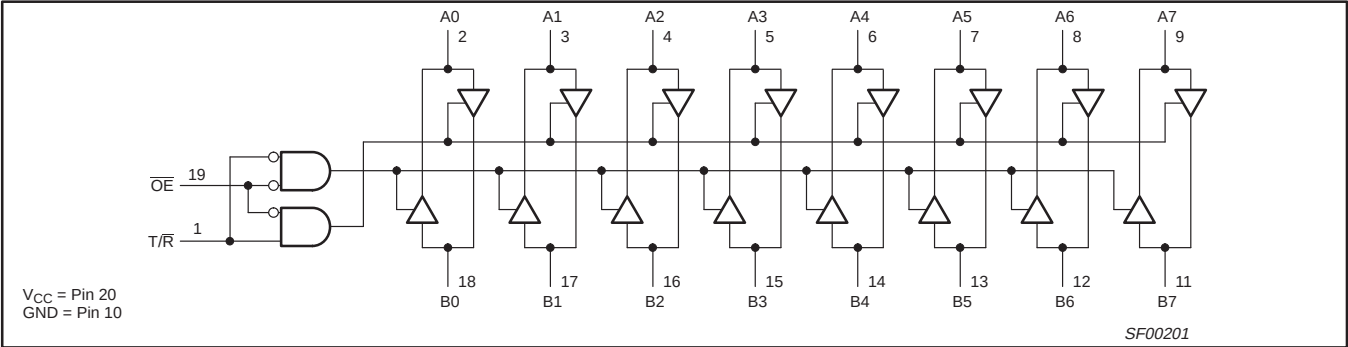
IEC/IEEE SYMBOL



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LOGIC DIAGRAM



FUNCTION TABLE

INPUTS		OUTPUTS
$\overline{OE}$	T/ $\overline{R}$	
L	L	Bus B data to Bus A
L	H	Bus A data to Bus B
H	X	Z

H = High voltage level
L = Low voltage level
X = Don't care
Z = High impedance "off" state

ABSOLUTE MAXIMUM RATINGS

(Operation beyond the limits set forth in this table may impair the useful life of the device.
Unless otherwise noted these limits are over the operating free-air temperature range.)

SYMBOL	PARAMETER		RATING	UNIT
V_{CC}	Supply voltage		−0.5 to +7.0	V
V_{IN}	Input voltage		−0.5 to +7.0	V
I_{IN}	Input current		−30 to +5	mA
V_{OUT}	Voltage applied to output in High output state		−0.5 to +5.5	V
I_{OUT}	Current applied to output in Low output state	A0–A7	48	mA
		B0–B7	128	mA
T_{amb}	Operating free-air temperature range		0 to +70	°C
T_{stg}	Storage temperature range		−65 to +150	°C

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	LIMITS			UNIT
		MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5.0	5.5	V
V_{IH}	High-level input voltage	2.0			V
V_{IL}	Low-level input voltage			0.8	V
I_{IK}	Input clamp current			−18	mA
I_{OH}	High-level output current	A0–A7		−3	mA
		B0–B7		−15	mA
I_{OL}	Low-level output current	A0–A7		24	mA
		B0–B7		64	mA
T_{amb}	Operating free-air temperature range	0		+70	°C

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DC ELECTRICAL CHARACTERISTICS

(Over recommended operating free-air temperature range unless otherwise noted.)

SYMBOL	PARAMETER		TEST CONDITIONS ¹			LIMITS			UNIT
						MIN	TYP ²	MAX	
V _{OH}	High-level output voltage	A0–A7, B0–B7	V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN	I _{OH} = –3mA	±10% V _{CC}	2.4			V
					±5% V _{CC}	2.7	3.4		V
		B0–B7		I _{OH} = –15mA	±10% V _{CC}	2.0			V
					±5% V _{CC}	2.0			V
V _{OL}	Low-level output voltage	A0–A7	V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN	I _{OL} = 20mA	±10% V _{CC}		0.30	0.50	V
				I _{OL} = 24mA	±5% V _{CC}		0.35	0.50	V
		B0–B7		I _{OL} = MAX	±10% V _{CC}			0.55	V
V _{OL}	Low-level output voltage	B0–B7	V _{CC} = MIN, V _{IL} = MAX, V _{IH} = MIN	I _{OL} = MAX	±5% V _{CC}		0.42	0.55	V
V _{IK}	Input clamp voltage		V _{CC} = MIN, I _I = I _{IK}				–0.73	–1.2	V
I _I	Input current at maximum input voltage	OE, T/R	V _{CC} = 5.5V, V _I = 7.0V					100	μA
		A0–A7, B0–B7	V _{CC} = 5.5V, V _I = 5.5V					1	mA
I _{IH}	High-level input current	OE, T/R only	V _{CC} = MAX, V _I = 2.7V					20	μA
I _{IL}	Low-level input current	OE, T/R only	V _{CC} = MAX, V _I = 0.5V					–1.2	mA
I _{IH} +I _{OZH}	Off-state output current High level voltage applied		V _{CC} = MAX, V _O = 2.7V					70	μA
I _{IL} +I _{OZL}	Off-state output current Low level voltage applied		V _{CC} = MAX, V _O = 0.5V					–600	μA
I _{OS}	Short-circuit output current ³	A0–A7	V _{CC} = MAX			–60		–150	mA
		B0–B7				–100		–225	mA
I _{CC}	Supply current (total)	I _{CC} H	V _{CC} = MAX				60	87	mA
		I _{CC} L					70	100	mA
		I _{CC} Z					75	110	mA

NOTES:

- For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions for the applicable type.
- All typical values are at V_{CC} = 5V, T_{amb} = 25°C.
- Not more than one output should be shorted at a time. For testing I_{OS}, the use of high-speed test apparatus and/or sample-and-hold techniques are preferable in order to minimize internal heating and more accurately reflect operational values. Otherwise, prolonged shorting of a High output may raise the chip temperature well above normal and thereby cause invalid readings in other parameter tests. In any sequence of parameter tests, I_{OS} tests should be performed last.

AC ELECTRICAL CHARACTERISTICS

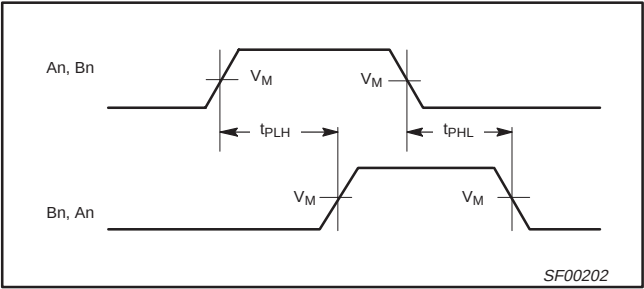
SYMBOL	PARAMETER	TEST CONDITION	LIMITS					UNIT
			V _{CC} = +5.0V T _{amb} = +25°C C _L = 50pF, R _L = 500Ω			V _{CC} = +5.0V ± 10% T _{amb} = 0°C to +70°C C _L = 50pF, R _L = 500Ω		
			MIN	TYP	MAX	MIN	MAX	
t _{PLH} t _{PHL}	Propagation delay An to Bn, Bn to An	Waveform 1	2.5 2.5	3.5 4.0	6.0 6.0	2.5 2.5	7.0 7.0	ns
t _{PZH} t _{PZL}	Output Enable time to High or Low level	Waveform 2 Waveform 3	2.0 3.5	4.5 5.5	7.0 8.0	2.0 3.5	8.0 9.0	ns
t _{PHZ} t _{PLZ}	Output Disable time from High or Low level	Waveform 2 Waveform 3	2.5 1.0	5.0 3.5	6.5 6.0	2.0 1.0	7.5 7.0	ns

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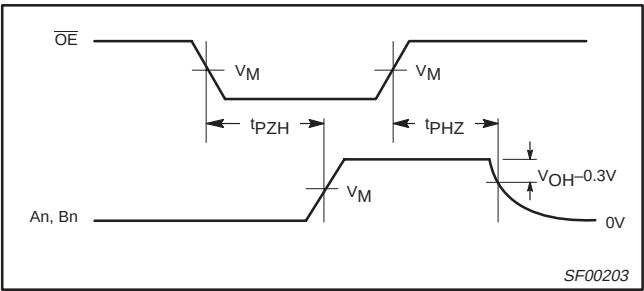
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AC WAVEFORMS

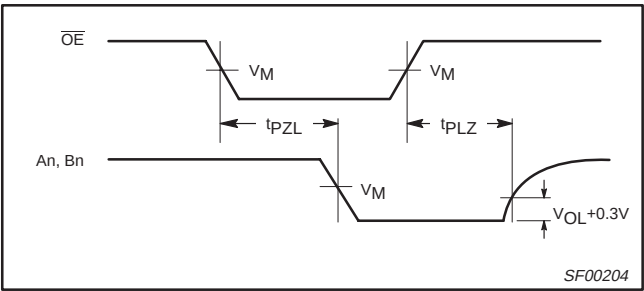
For all waveforms, $V_M = 1.5V$.



Waveform 1. Propagation Delay for Non-Inverting Output

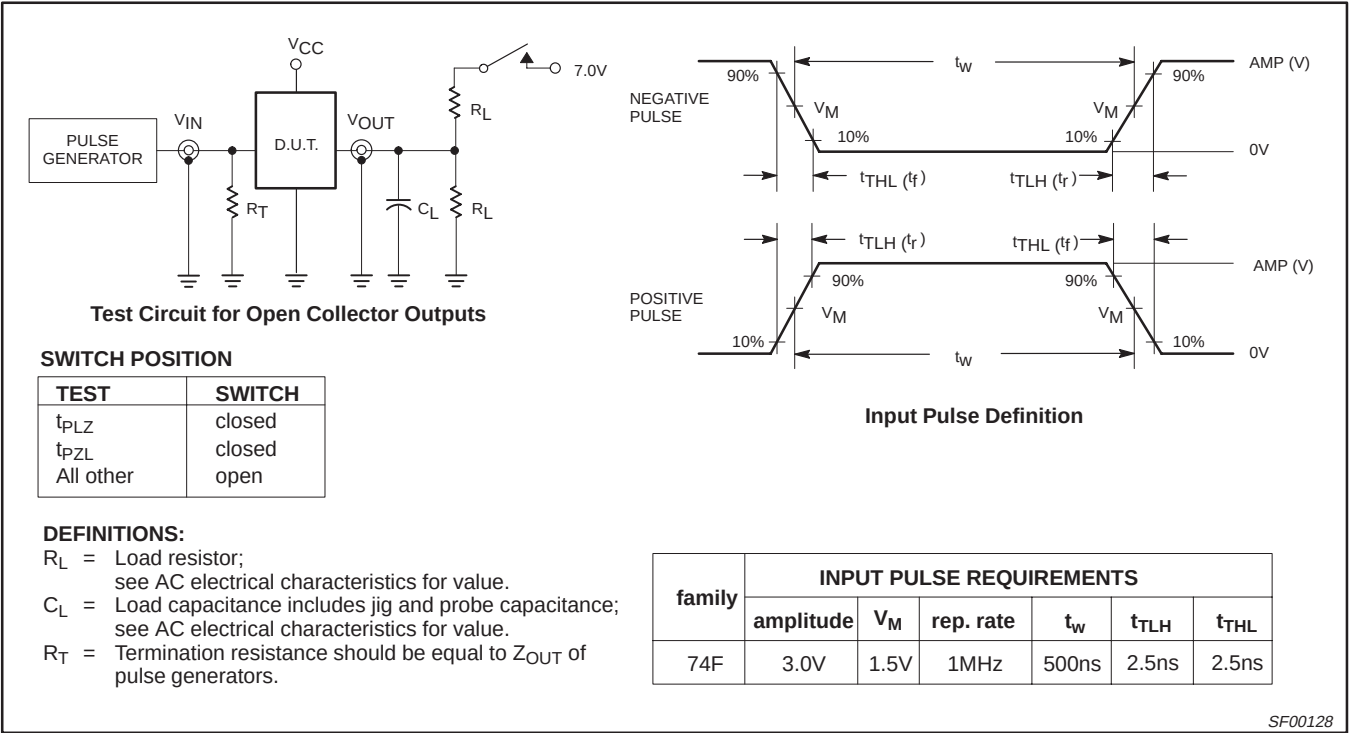


Waveform 2. 3-State Output Enable Time to High Level and Output Disable Time from High Level



Waveform 3. 3-State Output Enable Time to Low Level and Output Disable Time from Low Level

TEST CIRCUIT AND WAVEFORMS

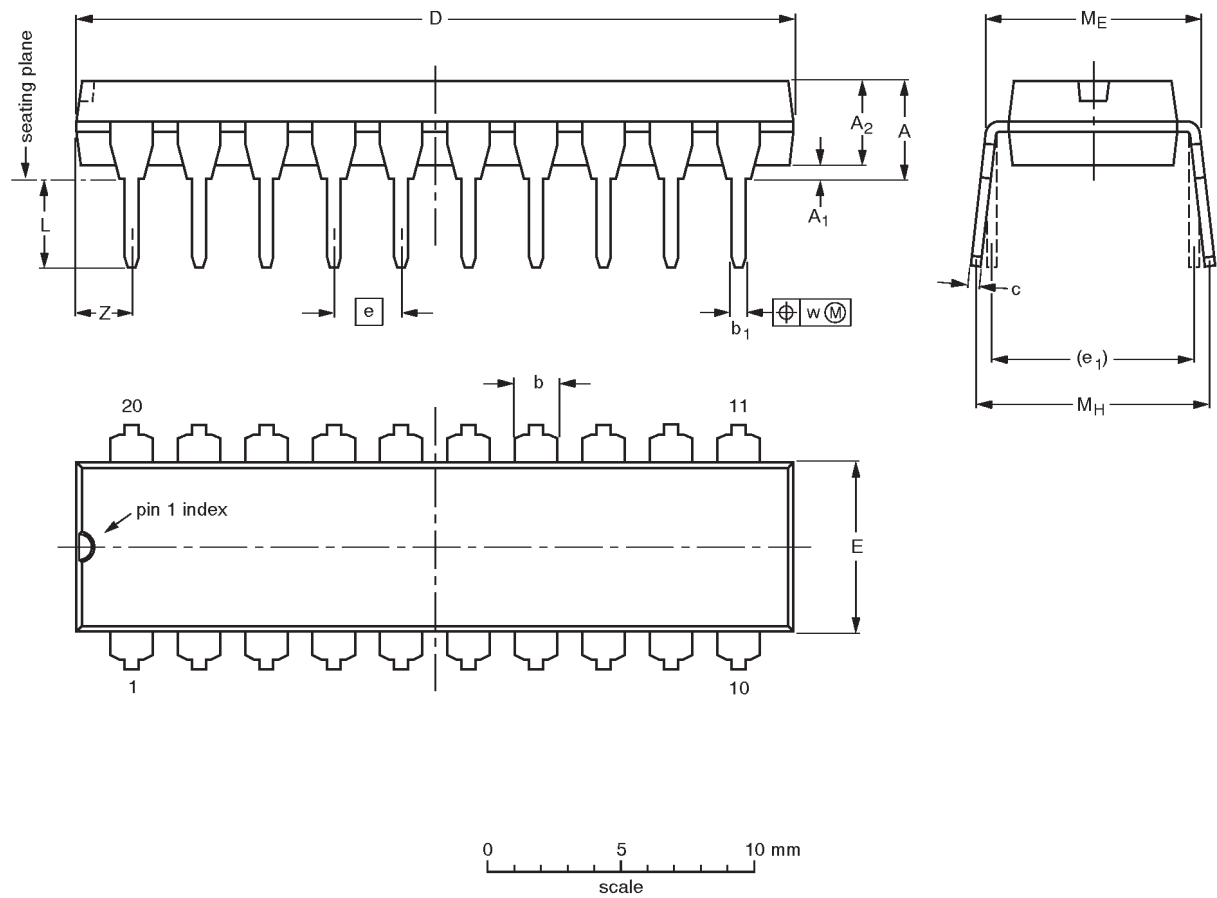


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DIP20: plastic dual in-line package; 20 leads (300 mil)

SOT146-1



DIMENSIONS (inch dimensions are derived from the original mm dimensions)

UNIT	A max.	A ₁ min.	A ₂ max.	b	b ₁	c	D ⁽¹⁾	E ⁽¹⁾	e	e ₁	L	M _E	M _H	w	Z ⁽¹⁾ max.
mm	4.2	0.51	3.2	1.73 1.30	0.53 0.38	0.36 0.23	26.92 26.54	6.40 6.22	2.54	7.62	3.60 3.05	8.25 7.80	10.0 8.3	0.254	2.0
inches	0.17	0.020	0.13	0.068 0.051	0.021 0.015	0.014 0.009	1.060 1.045	0.25 0.24	0.10	0.30	0.14 0.12	0.32 0.31	0.39 0.33	0.01	0.078

Note
1. Plastic or metal protrusions of 0.25 mm maximum per side are not included.

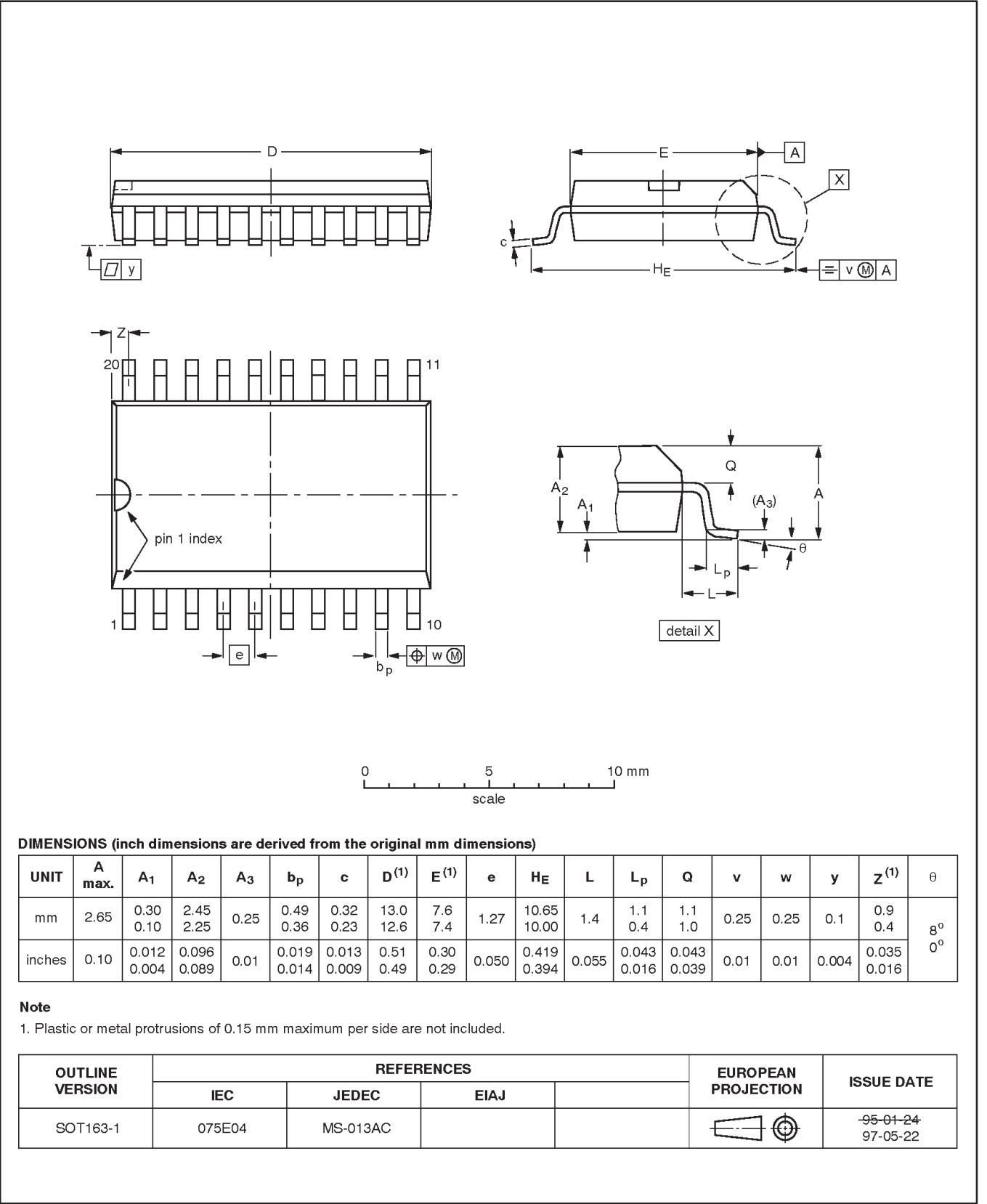
OUTLINE VERSION	REFERENCES				EUROPEAN PROJECTION	ISSUE DATE
	IEC	JEDEC	EIAJ			
SOT146-1			SC603			92-11-17 95-05-24

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SO20: plastic small outline package; 20 leads; body width 7.5 mm

SOT163-1



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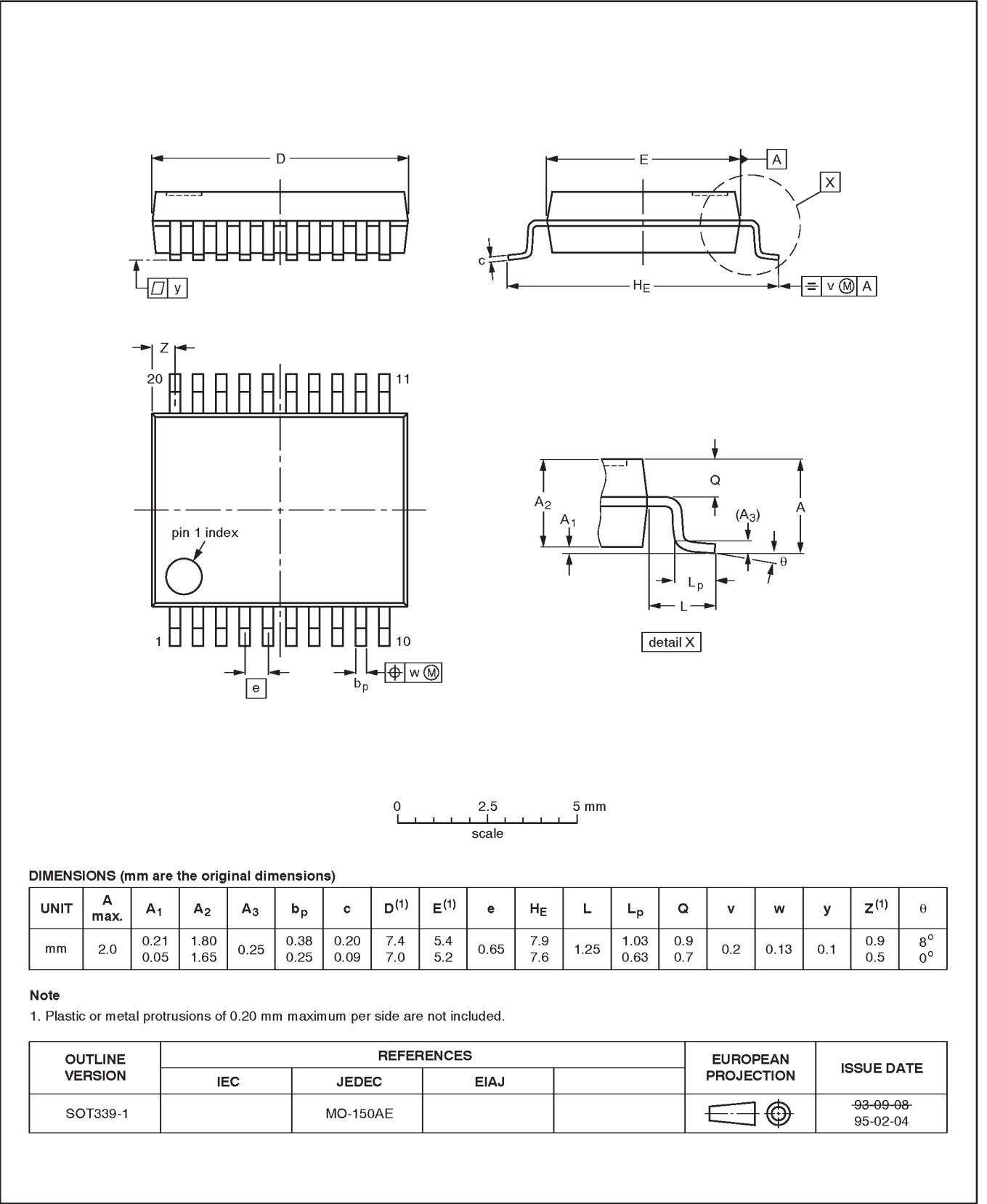
NOTES

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SSOP20: plastic shrink small outline package; 20 leads; body width 5.3 mm

SOT339-1



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DEFINITIONS		
Data Sheet Identification	Product Status	Definition
Objective Specification	Formative or in Design	This data sheet contains the design target or goal specifications for product development. Specifications may change in any manner without notice.
Preliminary Specification	Preproduction Product	This data sheet contains preliminary data, and supplementary data will be published at a later date. Philips Semiconductors reserves the right to make changes at any time without notice in order to improve design and supply the best possible product.
Product Specification	Full Production	This data sheet contains Final Specifications. Philips Semiconductors reserves the right to make changes at any time without notice, in order to improve design and supply the best possible product.

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